Melting Temperature and Wetting Angle of AlN/Dy₂O₃ and AlN/Yb₂O₃ Mixtures on SiC Substrates

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This work aims to evaluate the melting temperature and wetting behavior of AlN/Re₂O₃ (Re = Dy, Yb) mixtures when in contact with SiC substrates at high temperatures, in order to define whether these compounds can be further used to induce a more effective liquid phase sintering of SiC-based products. The prepared samples were placed on SiC plates and thermally treated up to 1900 °C under argon. The melting point and spreading evolution of different compositions of AlN/Re₂O₃ on SiC were determined by analyzing images captured as a function of the heating temperature. The contact angle and melting point were measured using the ImageJ software and according to DIN 51730, respectively. Based on the obtained wetting curves, all evaluated conditions resulted in the decrease of the contact angle values with temperature. The mixtures presenting improved wetting (θ ~ 1° and 3°) on SiC plates were the ones above the selected eutectic point.

Keywords: SiC, AlN, rare earth oxides, wettability, contact angle

1. Introduction

The sintering process of ceramics can be sped up in the presence of liquid phases, allowing a significant reduction of the temperature and time required for an effective densification of the materials microstructure. Due to the limitations related to the solid phase sintering process of SiC-based products, the search for compounds that can induce liquid generation at high temperatures and, consequently, favor the sintering/densification transformations, is highly recommended in order to develop ceramics with better performance. Furthermore, not only the type but also the amount of additives (used to result in the liquid phase formation) will have a major effect on the mechanical properties of the SiC obtained via liquid phase sintering (LPS).

Negita reported that rare earth oxides (Re₂O₃) show greater stability when interacting with silicon carbide at high temperatures. Moreover, the blend of aluminum nitride (AlN) with these compounds is also an effective alternative to optimize the properties (i.e. fracture toughness, etc.) of such ceramic. Based on the various investigations presented in the literature, the following systems have been evaluated for this purpose: AlN – Re₂O₃ (Re = Y, La e Nd)[5], AlN – Y₂O₃[6,7], AlN – Re₂O₃ (Re = Y e Yb)[8], AlN – Re₂O₃ (Re = Y, Er e Yb)[9], AlN – Re₂O₃ (Re = Y, Yb, Er, Lu, Ho, Sm e Ce)[10], AlN – Re₂O₃ (Re = Y, Yb, La)[11].

Considering the available phase diagrams for rare earth oxides - aluminum nitride, AlN-Y₂O₃ system has been the most investigated one. Based on thermodynamic calculations, Kaufman et al. predicted a diagram for this latter system, highlighting that a simple eutectic transformation could describe the equilibrium among the various phases.

Jeutter indicated via experimental tests that the eutectic composition could be attained for compositions comprising approximately 43% mol of AlN + 57% mol of Y₂O₃. Aiming to understand the SiC sintering process in the presence of AlN-Re₂O₃ for the in situ liquid-phase formation, the study of different parameters (i.e., interfacial energy between solid and liquid phases, surface tension, liquid penetration along grain boundaries of the solid-solid contacts (dihedral angle), wetting (contact angle), and infiltration by capillary action) are of most importance.

For instance, after the liquid generation during the LPS, the resultant microstructure of the consolidated ceramics should contain solid, liquid and vapor phases. With the liquid spreading on the solid surface, the decrease of the solid-vapor interface, followed by the increase of solid-liquid and liquid-vapor ones, should take place. Figure 1 illustrates the usual liquid spreading evolution when a good or poor wetting is detected on a solid surface. Young’s equation suitably describes the equilibrium condition reached for a system in the horizontal plane, where the contact angle (θ) is associated with the balance of three interfacial energies, γSL, γSV, and γLV (Equation 1).

\[ \gamma_{LV} \cos \theta = \gamma_{SV} - \gamma_{SL} \]  

(1)

The letters S, L, and V represent solid, liquid, and vapor components, respectively. The \( \gamma_{LV} - \gamma_{SL} \) difference is the wetting driving force and the solid should be wetted when \( \gamma_{LV} \cos \theta > 0 \).
The work of adhesion ($W_a$) between solid and liquid can be expressed by the Dupre’s equation as follows:

$$W_a = \gamma_{LV} + \gamma_{SV} - \gamma_{SL}$$  \hspace{1cm} (2)

The combination of Equations 1 and 2 give rise to the Young-Dupre equation:

$$W_a = \gamma_{LV} (\cos \theta + 1)$$  \hspace{1cm} (3)

and when $\theta = 0$, $\cos \theta$ will be equal to 1, resulting in the following:

$$W_a = 2\gamma_{LV}$$  \hspace{1cm} (4)

Equation 4 shows that $W_a$ (work of adhesion) is equivalent to twice the value of the liquid surface tension, which is related to the minimum energy required to break the liquid column per unit of area. In this case, the liquid-solid work of adhesion is equivalent or exceeds the cohesion work of the liquid, allowing this phase to spread on the solid surface.

It is accepted that: (i) for $\theta > 90^\circ$, the liquid will not wet the solid material, (ii) when $\theta < 90^\circ$, there will be the surface wetting and the liquid should spontaneously spread on it, (iii) when $\theta \approx 0^\circ$, the liquid should spread on the solid indefinitely, resulting in a complete wetting of the considered surface. It is important to highlight that, considering the liquid phase sintering process of ceramic materials, a suitable condition to favor the microstructure sintering is obtained when $\theta < 90^\circ$.

An alternative to evaluate liquid wettability consists in the measurement of the contact angle formed between the liquid and solid interface as a function of the temperature, time and liquid composition. The sessile drop technique is one of the most used experimental procedures for this purpose, as with a photographic system, images of the solid substrate + sample that will be melted (giving rise to the liquid phase when increasing the temperature) can be obtained, leading to an accurate determination of the shape evolution of the molten component. The contact angle is further calculated when $\theta < 90^\circ$.

### 2. Material and Methods

No AlN-Dy$_2$O$_3$ and AlN-Yb$_2$O$_3$ phase diagrams could be found in the consulted literature. However, due to the similar properties of the rare earth oxides, it was decided to take as reference the diagram shown in Figure 2 (AlN-Y$_2$O$_3$) for the selection of the compositions to be analyzed in this work.

Firstly, AlN-Dy$_2$O$_3$ and AlN-Yb$_2$O$_3$ mixtures equivalent to the eutectic point (43.05 mol% AlN and 56.95 mol% Re$_2$O$_3$, dotted vertical line 3 in Figure 2) were evaluated. Moreover, additional compositions near the eutectic point but containing the increment or reduction of 5 mol% or 10 mol% of Y$_2$O$_3$ (see dotted vertical lines in Figure 2) were also selected in order to identify which one of them would result in liquid phase generation at the lowest temperature. Table 1 presents details of the prepared AlN-Dy$_2$O$_3$ and AlN-Yb$_2$O$_3$ compositions.

It was used as precursor powder dysprosium oxide and ytterbium oxide with 99.9% purity supplied by ABCR GmbH & Co (< 1 μm) and aluminum nitride supplied by Hermann C. Starck Grade C (< 8 μm) - Germany. The raw materials were weighed on a precision scale (± 0.01 grams) according to the amounts defined in Table 1. After that, they were mixed in a planetary mill for 20 minutes (using isopropyl alcohol as liquid medium), dried at 110 °C for 24 hours and pressed into a cylindrical die with 4 mm diameter and 3 mm length.

For the wetting measurements, the pressed samples were placed on the top surface of prepared SiC plates (which had 98.9% of density). The set (pressed sample + SiC plate) was initially introduced in a graphite resistance furnace (ASTRO) and heated at a rate of 24 °C/min up to 1000 °C or 1800 °C for AlN/Dy$_2$O$_3$ or AlN/Yb$_2$O$_3$ compositions, respectively. After reaching this temperature, a lower heating rate was used (5 °C/min) under argon atmosphere at 1 atm, in order to define the materials’ melting point and analyze the spreading behavior of the liquid. The time effect on the wetting evolution of the prepared SiC substrates was analyzed with the use of one sample of each system (AlN-Dy$_2$O$_3$, AlN-Yb$_2$O$_3$), equivalent to the composition that presented the lower contact angle values. Therefore, after reaching the melting point of these mixtures, it was carried out a holding step at this temperature (by changing the power provided

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*Figure 1. Wetting of a liquid on the horizontal plane showing low and high contact angle*.

*Figure 2. AlN-Y$_2$O$_3$ phase diagram obtained by Jeutter*.
to the Astro furnace in order to keep the temperature at a constant value) to determine the time required to result in a complete wetting of the solid surface (equilibrium condition).

The changes in the shape of the AlN-Dy\textsubscript{2}O\textsubscript{3} e AlN-Yb\textsubscript{2}O\textsubscript{3} pressed samples on the SiC plate with temperature and time was observed by using an image capture system (Figure 3) to obtain the maximum liquid spreading. The contact angle values were determined with the analysis of the captured images using the ImageJ software (version 1.45s). Furthermore, the melting temperature of the AlN/Dy\textsubscript{2}O\textsubscript{3} e AlN/Yb\textsubscript{2}O\textsubscript{3} mixtures was calculated according to the procedure described in the DIN 51730 standard\textsuperscript{20}. After the furnace’s cooling down, the collected samples were cut and had their cross-section area ground, polished and coated with gold for the microstructural analysis. The liquid phase + SiC contact interface was analyzed via scanning electron microscope (SEM, LEO, model 1450VP) with energy dispersive spectrometer (EDS, Oxford INCA system).

3. Results and Discussion

Figure 4 shows the representative behavior of AlN/Dy\textsubscript{2}O\textsubscript{3} and AlN/Yb\textsubscript{2}O\textsubscript{3} mixtures on SiC plates with the increase of the temperature. Figure 4a and 4d indicate the condition where the pressed cylinders still presented their original shape, as the furnace’s temperatures were below the respective melting points of the evaluated materials. With the temperature increase, these samples changed their shape and the formation of a half-sphere (Figure 4b and 4e) represented the melting point of the mixtures, according to DIN51730 standard.

![Figure 3. Scheme of the wettability testing system\textsuperscript{17}.](image)

![Figure 4. Sequence of images obtained via CCD camera during the wetting measurements of AlN/Dy\textsubscript{2}O\textsubscript{3} (a-c) and AlN/Yb\textsubscript{2}O\textsubscript{3} representative mixtures (d-f) on SiC substrates.](image)

<table>
<thead>
<tr>
<th>Code\textsuperscript{*1}</th>
<th>mol %</th>
<th>weight %</th>
<th>Notes\textsuperscript{*2}</th>
</tr>
</thead>
<tbody>
<tr>
<td>Code\textsuperscript{*1}</td>
<td>AlN</td>
<td>Dy\textsubscript{2}O\textsubscript{3}</td>
<td>Yb\textsubscript{2}O\textsubscript{3}</td>
</tr>
<tr>
<td>1D</td>
<td>53.05</td>
<td>46.95</td>
<td>-</td>
</tr>
<tr>
<td>2D</td>
<td>48.05</td>
<td>51.95</td>
<td>-</td>
</tr>
<tr>
<td>3D</td>
<td>43.05</td>
<td>56.95</td>
<td>-</td>
</tr>
<tr>
<td>4D</td>
<td>38.05</td>
<td>61.95</td>
<td>-</td>
</tr>
<tr>
<td>5D</td>
<td>33.05</td>
<td>66.95</td>
<td>-</td>
</tr>
<tr>
<td>1Y</td>
<td>53.05</td>
<td>-</td>
<td>46.95</td>
</tr>
<tr>
<td>2Y</td>
<td>48.05</td>
<td>-</td>
<td>51.95</td>
</tr>
<tr>
<td>3Y</td>
<td>43.05</td>
<td>-</td>
<td>56.95</td>
</tr>
<tr>
<td>4Y</td>
<td>38.05</td>
<td>-</td>
<td>61.95</td>
</tr>
<tr>
<td>5Y</td>
<td>33.05</td>
<td>-</td>
<td>66.95</td>
</tr>
</tbody>
</table>

\textsuperscript{*1} D and Y indicate “dysprosium” and “ytterbium”, respectively. \textsuperscript{*2} A and B indicate “after” and “before” the eutectic composition, respectively.
Furthermore, Figure 4c and 4f also indicate the complete spreading of the liquid phase on the SiC plates.

Figure 5 shows the contact angle evolution with temperature and, a general trend observed was the decrease of \( \theta \) with the increase of the temperature. This behavior was associated to the reduction of the solid/liquid interfacial energy, that according Equation 1, favoring the liquid spreading at high temperature. Compositions 4D and 5Y presented the smallest contact angles, indicating the better wetting and spreading of the liquid phases. Moreover, all evaluated compositions exhibited very good wettability (\( \theta \ll 90^\circ \)) with final contact angles smaller than 10°. Such results are in tune with the data related to compositions of the AlN/Y\(_2\)O\(_3\) system (measured contact angle \( \sim 6^\circ \) at 1870 °C).

Table 2 shows the melting temperature (MT), initial (CA\(_i\)) and final (CA\(_f\)) contact angle of the evaluated compositions.

<table>
<thead>
<tr>
<th>Mixtures</th>
<th>AlN-Dy(_2)O(_3)</th>
<th>AlN-Yb(_2)O(_3)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>code</td>
<td>1D</td>
</tr>
<tr>
<td>MT (°C)</td>
<td></td>
<td>1767</td>
</tr>
<tr>
<td>CA(_i) (°)</td>
<td></td>
<td>51</td>
</tr>
<tr>
<td>CA(_f) (°)</td>
<td></td>
<td>5</td>
</tr>
</tbody>
</table>

Figure 6. Contact angle (\( \theta \)) versus time (t) for the 4D and 5Y mixtures on SiC substrates.

Figure 6 illustrates the contact angle behavior versus time for the mixtures that presented the lowest \( \theta \) values (4D and 5Y) considering isothermal conditions and keeping the samples at the temperatures indicated in Table 2. Based on these tests, the maximum spreading (complete wetting of the SiC surface) was obtained after approximately 3 and 4 minutes for the 4D and 5Y samples, respectively. The \( \theta \) decay for 4D mixture was initially faster than for 5Y and this behavior might be associated to viscosity of the formed liquid, as this property is one of the main factors influencing the liquid spreading speed and considering that the quality of the surfaces of the SiC plates were the same.
Figure 7a and 7d present the images of the interface area of SiC plate + 4D or 5Y compositions. The Dy₂O₃-AlN-based sample showed a uniform spreading on the solid surface with the generation of a continuous and dense layer of the resultant material. On the other hand, the analysis of the liquid-solid contact area for the mixture containing Yb₂O₃-AlN confirmed that a non-homogeneous layer presenting regions with high or low thickness was generated after exposing this material to 1850 °C.

According to semi-quantitative EDS analyses of the SiC substrate, Dy and Yb elements could be identified in the area near the solid-liquid interface, and this latter compound was found in greater content (Dy: 8.96 wt% or Yb: 65.95 wt%), which suggests that liquid infiltration might have taken place into the SiC plate microstructure.

Further details of the samples’ microstructure can be observed in Figure 7b-e (secondary electrons mode) and 7c-f (backscattered electrons). EDS analyses of the region presented in Figure 7c indicated that the darkest region (1) is comprised by C - Al - Si, suggesting that a partial dissolution of SiC took place into the liquid phase at high temperature, and the lighter area (2) is rich in Dy. The magnified region exhibited in Figure 7f (3) points out the presence of very small hexagonal crystals containing C - N – Al, also indicating the silicon carbide dissolution into the liquid and possibly a further precipitation of AlN.

4. Conclusions

According to the obtained results, the wettability of SiC surface depends strongly on the temperature, as the resultant contact angle of the molten AlN/Re₂O₃ compositions presented a major decrease at higher temperatures, leading to the liquid spreading on the solid plates. The evaluated rare earth oxides (Dy₂O₃ and Yb₂O₃) showed similar wetting behavior on the silicon carbide substrates. AlN/Dy₂O₃ and AlN/Yb₂O₃ mixtures presented final contact angles smaller than 10°, which can allow their use as efficient additives for the liquid phase sintering of SiC-based ceramics.

The compositions of rare earth oxides above the supposed eutectic point (AlN 43.05% - 56.95 mol% Re₂O₃) resulted in liquid infiltration in the SiC plate. The liquid spreading behavior as a function of time (isothermal condition) indicated that the AlN/Dy₂O₃ composition presented a more significant
References


